

GE-222 **REPLACES** **ECG287 • SK3433**

NPN SILICON TRANSISTOR

| | |
|-------|-------|
| BVCBO | 300V |
| BVCEO | 300V |
| BVEBO | 6V |
| IC | 500MA |
| PD | 625MW |
| FREQ | 50MHZ |
| HFE | 40 |

E B C



TO-92
BOTTOM VIEW

COMPLEMENT TO GE-223
USA



See your GE REPLACEMENT SEMICONDUCTOR GUIDE
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